



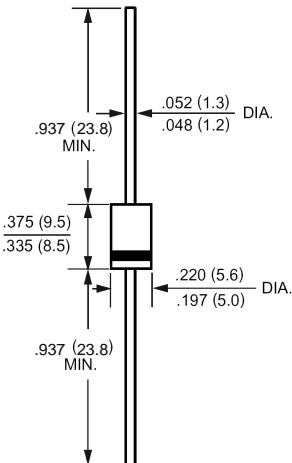
# SF51G THRU SF58G

## Superfast Recovery Rectifiers

### FEATURES

- Glass Passivated chip junction
- High surge capability
- Low forward voltage, high current capability
- Hermetically sealed
- Superfast recovery times
- Exceeds environmental standards of MIL-S-19500/228
- Low leakage.

DO-201AD(DO-27)



### MECHANICAL DATA

Case: Molded plastic, DO-201AD

Epoxy: UL 94V-O rate flame retardant

Lead: Axial leads, solderable per MIL-STD-202,  
method 208 guaranteed

Polarity: Color band denotes cathode end

Mounting position: Any

Weight: 0.04ounce, 1.1gram

Dimensions in inches and (millimeters)

### Maximum Ratings and Electrical Characteristics

Ratings at 25°C ambient temperature unless otherwise specified.

Single phase, half wave, 60Hz, resistive or inductive load.

For capacitive load, derate current by 20%.

	Symbols	SF51G	SF52G	SF53G	SF54G	SF55G	SF56G	SF58G	Units
Maximum Recurrent Peak Reverse Voltage	V <sub>RRM</sub>	50	100	150	200	300	400	650	Volts
Maximum RMS Voltage	V <sub>RMS</sub>	35	70	105	140	210	280	450	Volts
Maximum DC Blocking Voltage	V <sub>DC</sub>	50	100	150	200	300	400	650	Volts
Maximum Average Forward Rectified Current .375"(9.5mm) Lead Length at T <sub>A</sub> =55	I <sub>(AV)</sub>				5.0				Amp
Peak Forward Surge Current, 8.3ms single half-sine-wave superimposed on rated load (JEDEC method)	I <sub>FSM</sub>				150				Amp
Maximum Forward Voltage at 5.0A DC and 25	V <sub>F</sub>		1.0			1.25		1.65	Volts
Maximum Reverse Current at T <sub>A</sub> =25 at Rated DC Blocking Voltage T <sub>A</sub> =100	I <sub>R</sub>			5.0					uAmp
Typical Junction Capacitance (Note 1)	C <sub>J</sub>			45					pF
Typical Thermal Resistance (Note 2)	R <sub>θJA</sub>			25					/W
Maximum Reverse Recovery Time (Note 3)	T <sub>RR</sub>			35					nS
Operating Junction Temperature Range	T <sub>J</sub>			-55 to +150					
Storage Temperature Range	T <sub>Stg</sub>			-55 to +150					

### NOTES:

1- Measured at 1 MHz and applied reverse voltage of 4.0 VDC.

2- Thermal Resistance Junction to Ambient and form junction to lead at 0.375"(9.5mm) lead length P.C.B. Mounted.

3- Reverse Recovery Test Conditions : I<sub>F</sub>=.5A , I<sub>R</sub>=1A , I<sub>RR</sub>=.25A.



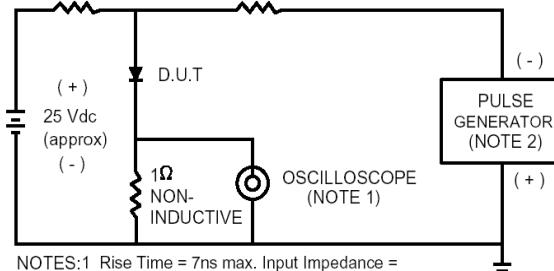
# SF51G THRU SF58G

## Superfast Recovery Rectifiers

### RATINGS AND CHARACTERISTIC CURVES

FIG. 1 - TEST CIRCUIT DIAGRAM AND REVERSE RECOVERY TIME CHARACTERISTIC

50Ω  
NONINDUCTIVE      10Ω  
NONINDUCTIVE



NOTES: 1. Rise Time = 7ns max. Input Impedance = 1 megohm, 22pF.

2. Rise Time = 10ns max. Source Impedance = 50 ohms.

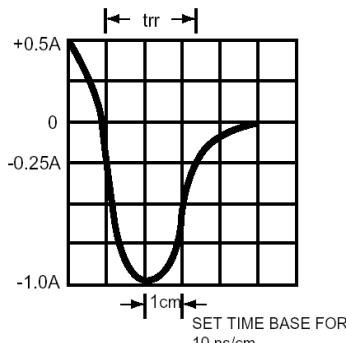


FIG. 2 - TYPICAL FORWARD CURRENT DERATING CURVE

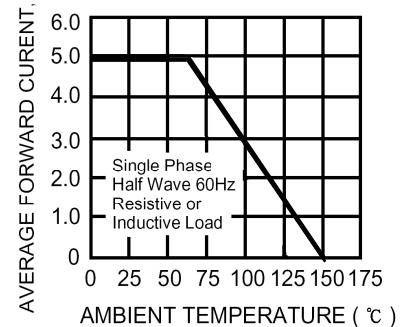


FIG. 3 - TYPICAL REVERSE CHARACTERISTICS

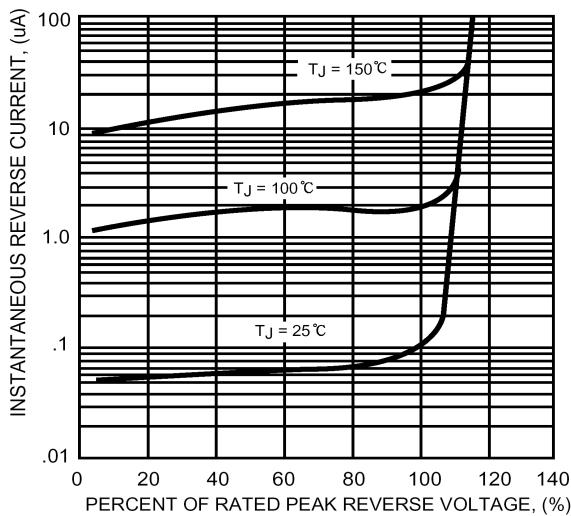


FIG. 4 - TYPICAL INSTANTANEOUS FORWARD CHARACTERISTICS

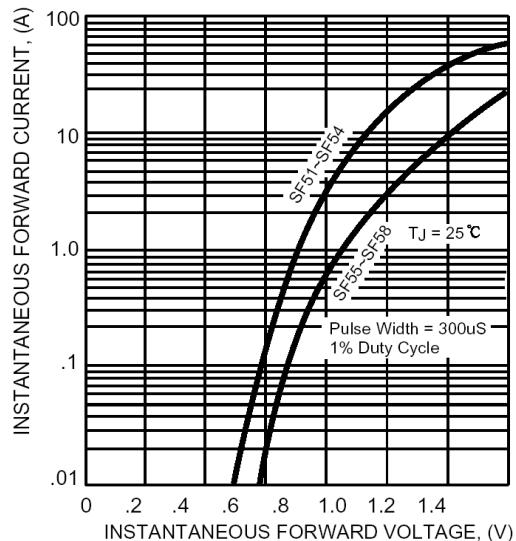


FIG. 5 MAXIMUM NON REPETITIVE PEAK

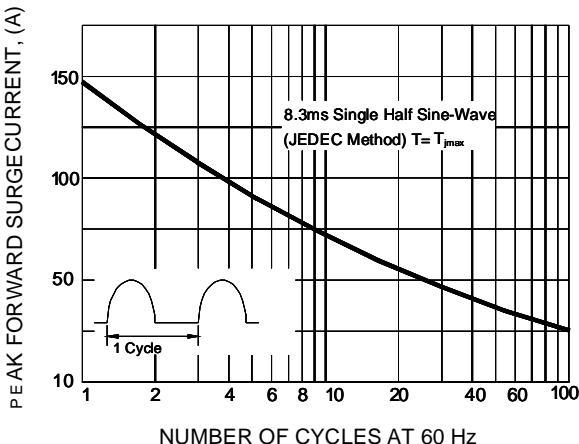


FIG. 6 - TYPICAL JUNCTION CAPACITANCE

